ULTRA SMALL, LOW INPUT VOLTAGE, LOW r_{ON}, LOAD SWITCHES

FEATURES

- **Low Input Voltage: 1.0 V to 3.6 V**
- **Ultra-Low ON Resistance**
  - **r_{ON} = 78 mΩ at V_{IN} = 3.6 V**
  - **r_{ON} = 93 mΩ at V_{IN} = 2.5 V**
  - **r_{ON} = 109 mΩ at V_{IN} = 1.8 V**
  - **r_{ON} = 146 mΩ at V_{IN} = 1.2 V**
- **500-mA Maximum Continuous Switch Current**
- **Ultra Low Quiescent Current: 82 nA at 1.8 V**
- **Ultra Low Shutdown Current: 44 nA at 1.8 V**
- **Low Control Input Thresholds Enable Use of 1.2-V/1.8-V/2.5-V/3.3-V Logic**
- **Controlled Slew Rate to Avoid Inrush Currents**
  - **TPS22901 and TPS22902: 40-μs t_r**
  - **TPS22902B: 220-μs t_r**
- **ESD Performance Tested Per JESD 22**
  - **2000-V Human-Body Model (A114-B, Class II)**
  - **1000-V Charged-Device Model (C101)**
- **Four-Terminal Wafer-Chip-Scale Package (WCSP)**
  - **0.8 mm × 0.8 mm, 0.4 mm Pitch, 0.5 mm Height**

APPLICATIONS

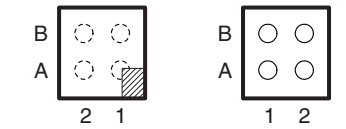
- **Personal Digital Assistants (PDAs)**
- **Cellular Phones**
- **GPS Devices**
- **MP3 Players**
- **Digital Cameras**
- **Peripheral Ports**
- **Portable Instrumentation**
- **RF Modules**

DESCRIPTION

TPS22901, TPS22902, and TPS22902B are ultra-small, low ON resistance (r_{ON}) load switches with controlled turn on. The devices contain a P-channel MOSFET that operates over an input voltage range of 1.0 V to 3.6 V. The switch is controlled by an on/off input (ON), which is capable of interfacing directly with low-voltage control signals. In TPS22902 and in TPS22902B, a 120-Ω on-chip load resistor is added for output quick discharge when the switch is turned off.

TPS22901, TPS22902, and TPS22902B are available in a space-saving 4-terminal WCSP with 0.4-mm pitch (YFP). The devices are characterized for operation over the free-air temperature range of –40°C to 85°C.

YFP PACKAGE



Laser Marking View **Bump View**

TERMINAL ASSIGNMENTS

B	ON	GND
A	V_{IN}	V_{OUT}
	2	**1**

	r_{ON} at 1.8 V (TYP)	SLEW RATE (TYP at 1.8 V)	QUICK OUTPUT DISCHARGE(1)	MAX OUTPUT CURRENT	ENABLE
TPS22901	109 mΩ	40 μs		500 mA	Active high
TPS22902	109 mΩ	40 μs	Yes	500 mA	Active high
TPS22902B	109 mΩ	220 μs	Yes	500 mA	Active high

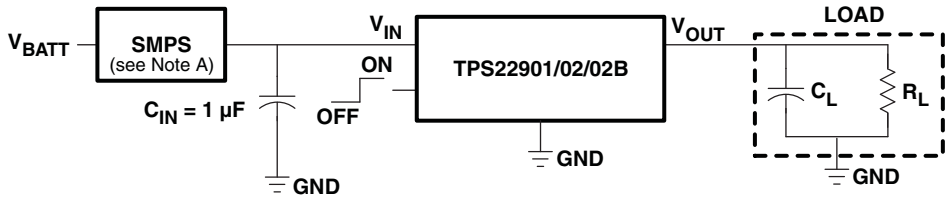
(1) This feature discharges the output of the switch to ground through a 120-Ω resistor, preventing the output from floating.

ORDERING INFORMATION

T_A	PACKAGE(1)(2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	WCSP – YFP (0.4 mm pitch)	Tape and reel	TPS22901YFPR	_ _ _3P _
			TPS22902YFPR	_ _ _3R _
			TPS22902BYFPR	_ _ _3S _

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

TYPICAL APPLICATION



A. Switched mode power supply

APPLICATION BLOCK DIAGRAM

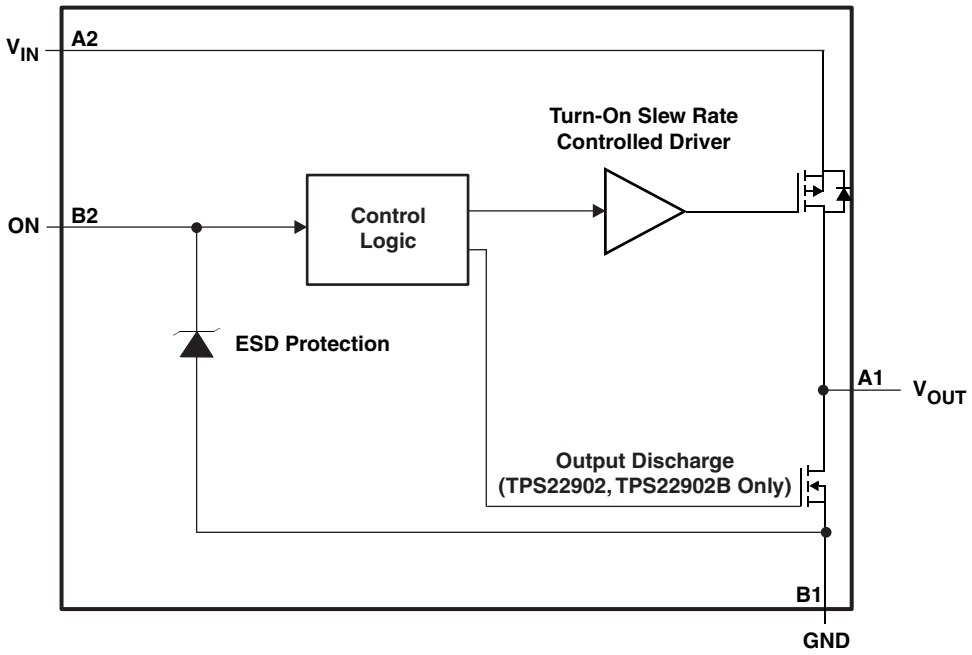


Figure 1. Functional Block Diagram

FUNCTION TABLE

ON (Control Input)	V_{IN} to V_{OUT}	V_{OUT} to GND (TPS22902, TPS22902B only)
L	OFF	ON
H	ON	OFF

TERMINAL FUNCTIONS

TERMINAL		DESCRIPTION
BALL NO.	NAME	
A1	V_{OUT}	Switch output
A2	V_{IN}	Switch input, bypass this input with a ceramic capacitor to ground
B1	GND	Ground
B2	ON	Switch control input, active high

ABSOLUTE MAXIMUM RATINGS(1)

			MIN	MAX	UNIT
V_{IN}	Input voltage range		–0.3	4	V
V_{OUT}	Output voltage range			V_{IN} + 0.3	V
V_{ON}	Input voltage range		–0.3	4	V
P	Power dissipation at T_A = 25°C			0.48	W
I_{MAX}	Maximum continuous switch current			500	mA
T_A	Operating free-air temperature range		–40	85	°C
T_{stg}	Storage temperature range		–65	150	°C
T_{lead}	Maximum lead temperature (10-s soldering time)			300	°C
ESD	Electrostatic discharge protection	Human-Body Model (HBM)		2000	V
		Charged Device Model (CDM)		1000	

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL IMPEDANCE RATINGS

				UNIT
θ_{JA}	Package thermal impedance(1)	YFP package	205	°C/W

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{IN}	Input voltage range	1	3.6	V
V_{OUT}	Output voltage range		V_{IN}	
V_{IH}	High-level input voltage, ON	0.85	3.6	V
V_{IL}	Low-level input voltage, ON		0.4	V
C_{IN}	Input capacitor	1(1)		µF

(1) See Application Information.

ELECTRICAL CHARACTERISTICS

V_{IN} = 1.0 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP(1)	MAX	UNIT
I_{IN}	Quiescent current	I_{OUT} = 0, V_{IN} = V_{ON}	V_{IN} = 1.1 V	Full		37	120	nA
			V_{IN} = 1.8 V	Full		82	235	
			V_{IN} = 3.6 V	Full		204	880	
$I_{IN(OFF)}$	OFF-state supply current	V_{ON} = GND, OUT = Open	V_{IN} = 1.1 V	Full		22	210	nA
			V_{IN} = 1.8 V	Full		44	260	
			V_{IN} = 3.6 V	Full		137	700	
$I_{IN(LEAKAGE)}$	OFF-state switch current	V_{ON} = GND, V_{OUT} = 0	V_{IN} = 1.1 V	Full		22	140	nA
			V_{IN} = 1.8 V	Full		45	230	
			V_{IN} = 3.6 V	Full		137	610	
r_{ON}	ON-state resistance	I_{OUT} = - 200 mA	V_{IN} = 3.6 V	25°C		78	95	mΩ
				Full			95	
			V_{IN} = 2.5 V	25°C		93	110	
				Full			110	
			V_{IN} = 1.8 V	25°C		109	130	
				Full			130	
			V_{IN} = 1.2 V	25°C		146	200	
				Full			200	
			V_{IN} = 1.1 V	25°C		174	330	
				Full			330	
r_{PD}	Output pulldown resistance	V_{IN} = 3.3 V, V_{ON} = 0, I_{OUT} = 30 mA (TPS22902/TPS22902B only)		25°C		88	120	Ω
I_{ON}	ON input leakage current	V_{ON} = 1.1 V to 3.6 V or GND		Full			25	nA

(1) Typical values are at the specified V_{IN} and T_A = 25°C.

SWITCHING CHARACTERISTICS

V_{IN} = 1.1 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TPS22901			TPS22902(1)			TPS22902B(1)			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{ON}	Turn-ON time	R_L = 500 Ω	C_L = 0.1 µF		108			108			531		µs
			C_L = 1 µF		131			131			596		
			C_L = 3.3 µF		153			153			659		
t_{OFF}	Turn-OFF time	R_L = 500 Ω	C_L = 0.1 µF		39			11			11		µs
			C_L = 1 µF		317			69			67		
			C_L = 3.3 µF		1105			238			225		
t_r	V_{OUT} rise time	R_L = 500 Ω	C_L = 0.1 µF		70			70			365		µs
			C_L = 1 µF		78			78			367		
			C_L = 3.3 µF		92			92			395		
t_f	V_{OUT} fall time	R_L = 500 Ω	C_L = 0.1 µF		107			18			21		µs
			C_L = 1 µF		966			175			189		
			C_L = 3.3 µF		3532			632			565		

(1) RL_CHIP = 120 Ω

SWITCHING CHARACTERISTICS

V_{IN} = 1.2 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TPS22901			TPS22902(1)			TPS22902B(1)			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{ON}	Turn-ON time	R_L = 500 Ω	C_L = 0.1 µF		96			96			471		µs
			C_L = 1 µF		116			116			527		
			C_L = 3.3 µF		135			135			587		
t_{OFF}	Turn-OFF time	R_L = 500 Ω	C_L = 0.1 µF		39			10			10		µs
			C_L = 1 µF		317			62			61		
			C_L = 3.3 µF		1110			210			199		
t_r	V_{OUT} rise time	R_L = 500 Ω	C_L = 0.1 µF		62			62			324		µs
			C_L = 1 µF		69			69			325		
			C_L = 3.3 µF		81			81			350		
t_f	V_{OUT} fall time	R_L = 500 Ω	C_L = 0.1 µF		109			17			20		µs
			C_L = 1 µF		995			163			175		
			C_L = 3.3 µF		3650			587			523		

(1) RL_CHIP = 120 Ω

SWITCHING CHARACTERISTICS

V_{IN} = 1.8 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TPS22901			TPS22902(1)			TPS22902B(1)			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{ON}	Turn-ON time	R_L = 500 Ω	C_L = 0.1 µF		61			61			302		µs
			C_L = 1 µF		72			72			335		
			C_L = 3.3 µF		83			83			367		
t_{OFF}	Turn-OFF time	R_L = 500 Ω	C_L = 0.1 µF		38			8			8		µs
			C_L = 1 µF		317			49			49		
			C_L = 3.3 µF		1135			169			167		
t_r	V_{OUT} rise time	R_L = 500 Ω	C_L = 0.1 µF		40			40			220		µs
			C_L = 1 µF		45			45			220		
			C_L = 3.3 µF		53			53			235		
t_f	V_{OUT} fall time	R_L = 500 Ω	C_L = 0.1 µF		111			15			15		µs
			C_L = 1 µF		1020			140			159		
			C_L = 3.3 µF		3700			517			481		

(1) RL_CHIP = 120 Ω

SWITCHING CHARACTERISTICS

V_{IN} = 2.5 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TPS22901			TPS22902(1)			TPS22902B(1)			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{ON}	Turn-ON time	R_L = 500 Ω	C_L = 0.1 µF		45			45			223		µs
			C_L = 1 µF		53			53			246		
			C_L = 3.3 µF		61			61			268		
t_{OFF}	Turn-OFF time	R_L = 500 Ω	C_L = 0.1 µF		38			7			7		µs
			C_L = 1 µF		314			46			47		
			C_L = 3.3 µF		1140			161			158		
t_r	V_{OUT} rise time	R_L = 500 Ω	C_L = 0.1 µF		32			32			175		µs
			C_L = 1 µF		35			35			175		
			C_L = 3.3 µF		41			41			187		
t_f	V_{OUT} fall time	R_L = 500 Ω	C_L = 0.1 µF		113			14			18		µs
			C_L = 1 µF		1040			139			185		
			C_L = 3.3 µF		3795			516			471		

(1) RL_CHIP = 120 Ω

SWITCHING CHARACTERISTICS

V_{IN} = 3 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TPS22901			TPS22902(1)			TPS22902B(1)			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{ON}	Turn-ON time	R_L = 500 Ω	C_L = 0.1 µF		38			38			191		µs
			C_L = 1 µF		45			45			211		
			C_L = 3.3 µF		53			53			231		
t_{OFF}	Turn-OFF time	R_L = 500 Ω	C_L = 0.1 µF		38			7			7		µs
			C_L = 1 µF		320			46			46		
			C_L = 3.3 µF		1145			53			156		
t_r	V_{OUT} rise time	R_L = 500 Ω	C_L = 0.1 µF		28			28			159		µs
			C_L = 1 µF		31			31			160		
			C_L = 3.3 µF		37			37			170		
t_f	V_{OUT} fall time	R_L = 500 Ω	C_L = 0.1 µF		114			14			17		µs
			C_L = 1 µF		1045			139			160		
			C_L = 3.3 µF		3815			509			473		

(1) RL_CHIP = 120 Ω

SWITCHING CHARACTERISTICS

V_{IN} = 3.6 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		TPS22901			TPS22902(1)			TPS22902B(1)			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{ON}	Turn-ON time	R_L = 500 Ω	C_L = 0.1 µF		33			33			166		µs
			C_L = 1 µF		39			39			183		
			C_L = 3.3 µF		46			46			201		
t_{OFF}	Turn-OFF time	R_L = 500 Ω	C_L = 0.1 µF		38			7			7		µs
			C_L = 1 µF		322			46			45		
			C_L = 3.3 µF		1145			156			155		
t_r	V_{OUT} rise time	R_L = 500 Ω	C_L = 0.1 µF		25			25			146		µs
			C_L = 1 µF		28			28			146		
			C_L = 3.3 µF		34			34			156		
t_f	V_{OUT} fall time	R_L = 500 Ω	C_L = 0.1 µF		116			14			17		µs
			C_L = 1 µF		1060			139			161		
			C_L = 3.3 µF		3840			512			475		

(1) RL_CHIP = 120 Ω

TYPICAL CHARACTERISTICS

TPS22901, TPS22902, TPS22902B

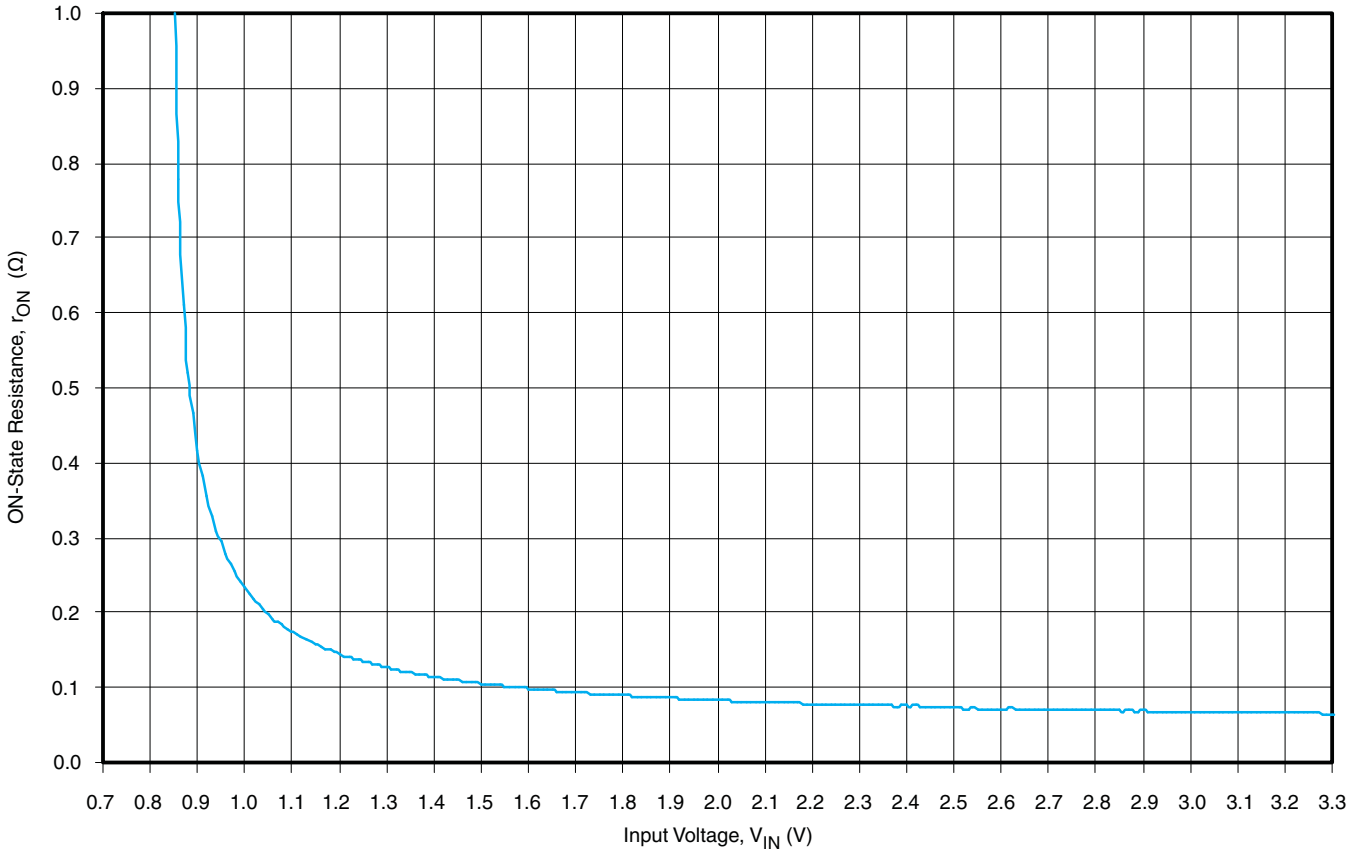


Figure 2. r_{ON} vs V_{IN}

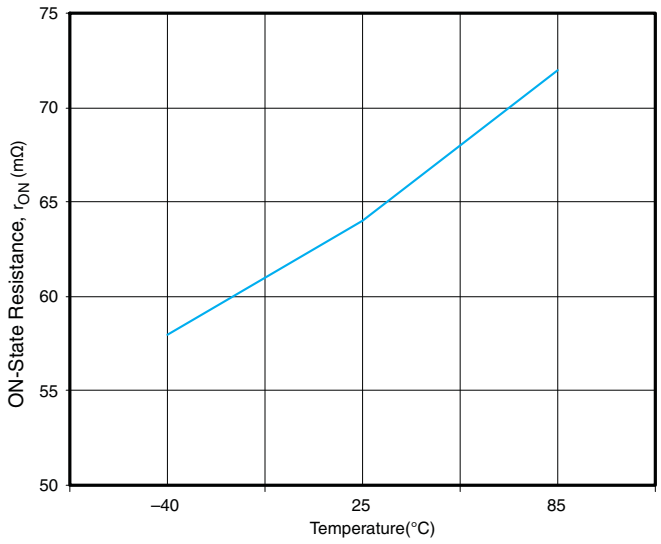


Figure 3. r_{ON} vs Temperature (V_{IN} = 3.3 V)

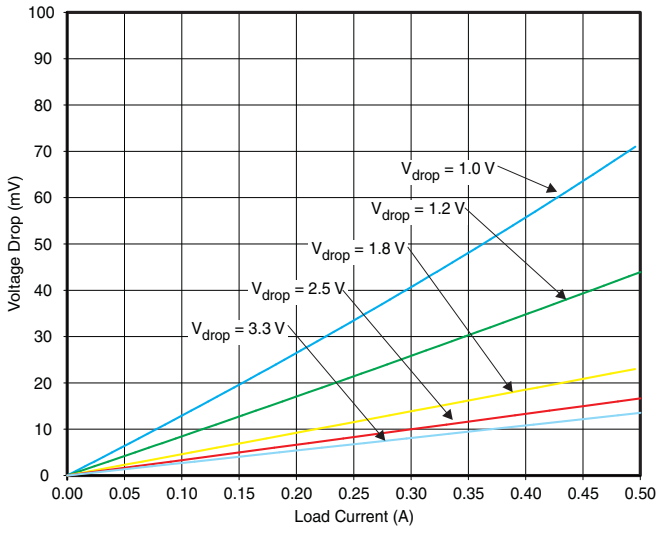


Figure 4. Voltage Drop vs. Load Current

TYPICAL CHARACTERISTICS (continued)

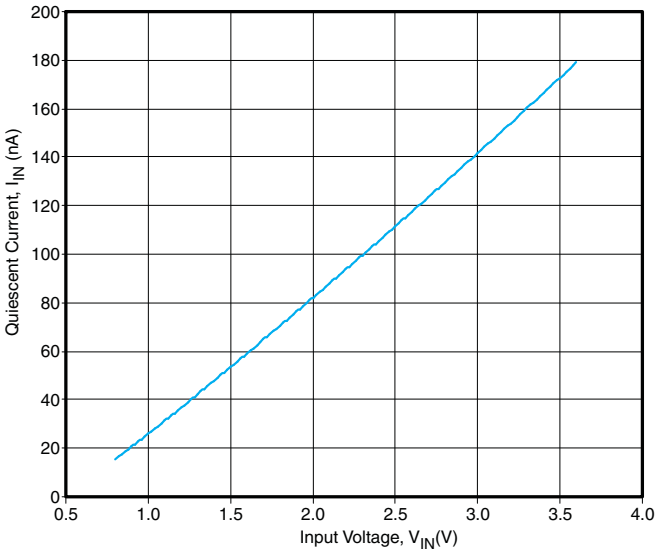


Figure 5. Quiescent Current vs V_{IN} (V_{ON} = V_{IN}, I_{OUT} = 0)

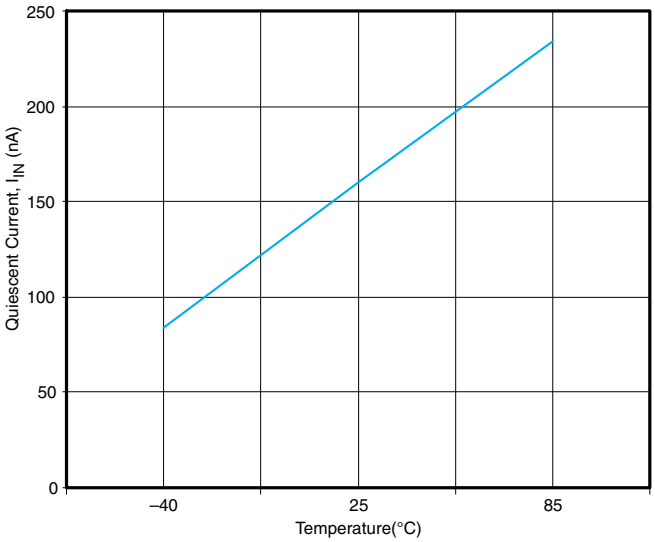


Figure 6. Quiescent Current vs Temperature (V_{IN} = 3.3 V, I_{OUT} = 0)

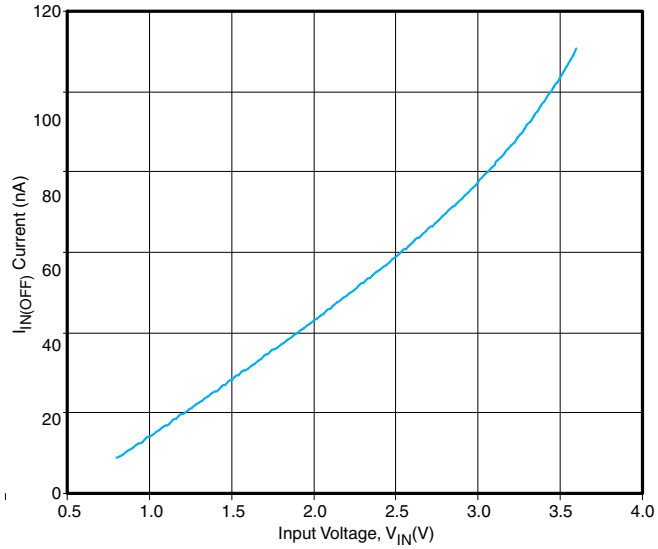


Figure 7. $I_{IN(OFF)}$ vs V_{IN} (V_{ON} = 0 V)

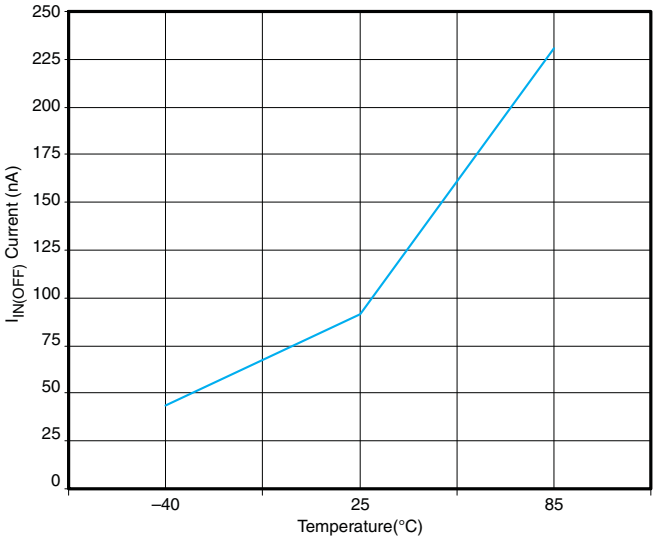


Figure 8. $I_{IN(OFF)}$ vs Temperature (V_{IN} = 3.3 V)

TYPICAL CHARACTERISTICS (continued)

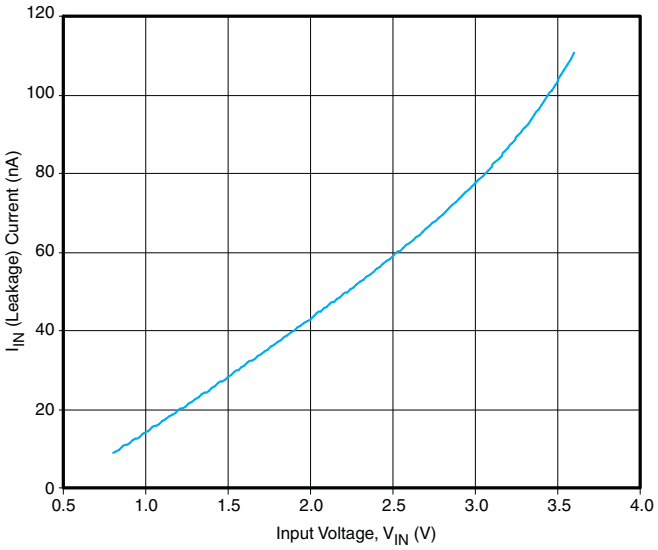


Figure 9. I_{IN}(Leakage) vs V_{IN} (I_{OUT} = 0)

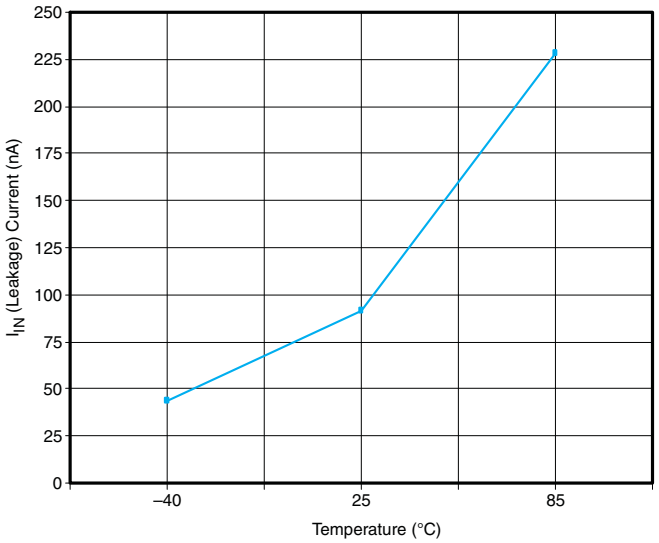


Figure 10. I_{IN} (Leakage) vs Temperature (V_{IN} = 3.3 V)

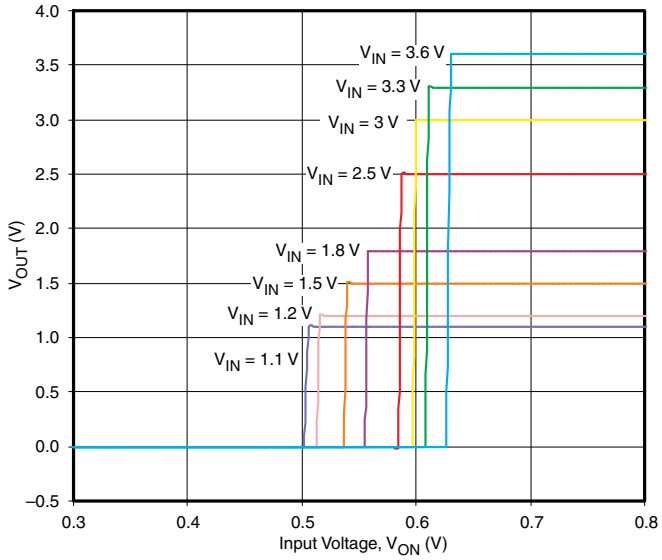


Figure 11. ON-Input Threshold

TYPICAL CHARACTERISTICS (continued)

TPS22901

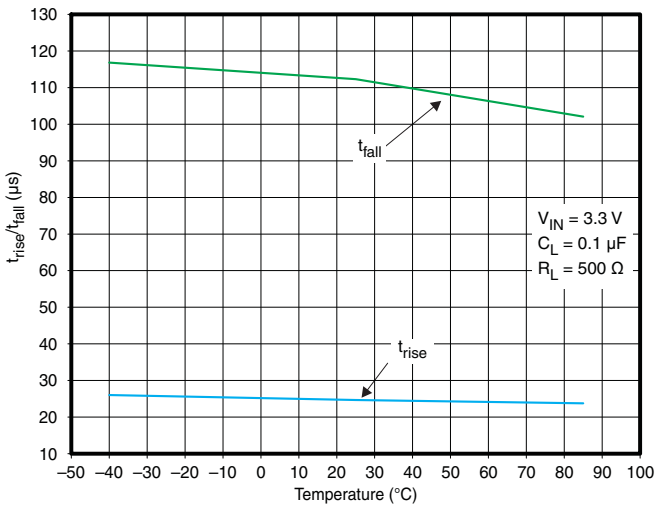


Figure 12. t_{rise}/t_{fall} vs Temperature

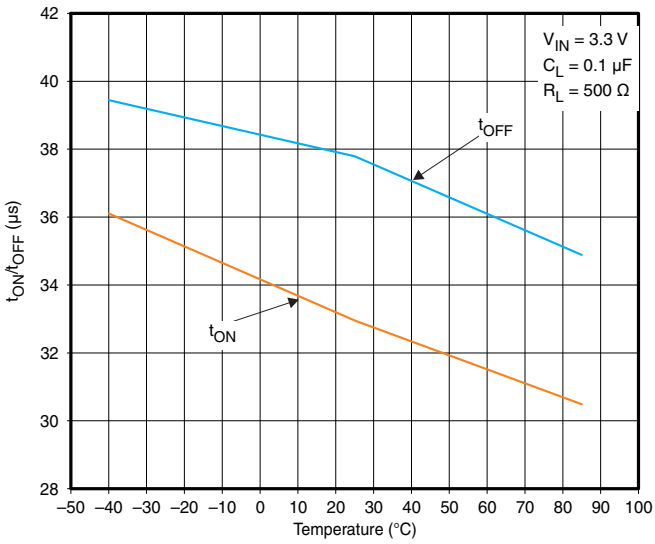


Figure 13. t_{ON}/t_{OFF} vs Temperature

TPS22902

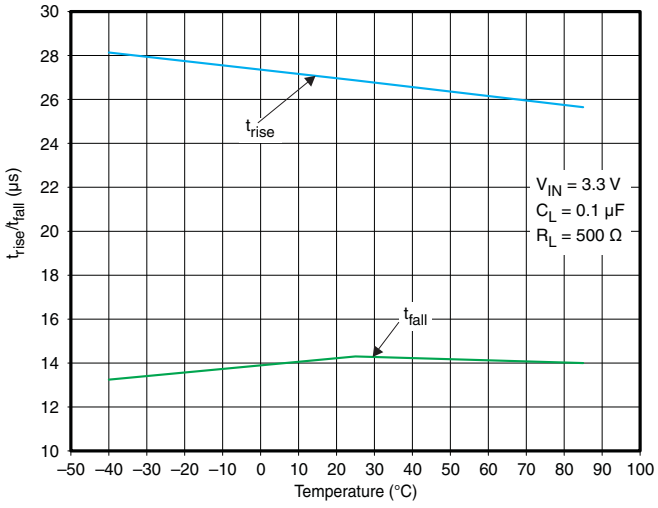


Figure 14. t_{rise}/t_{fall} vs Temperature

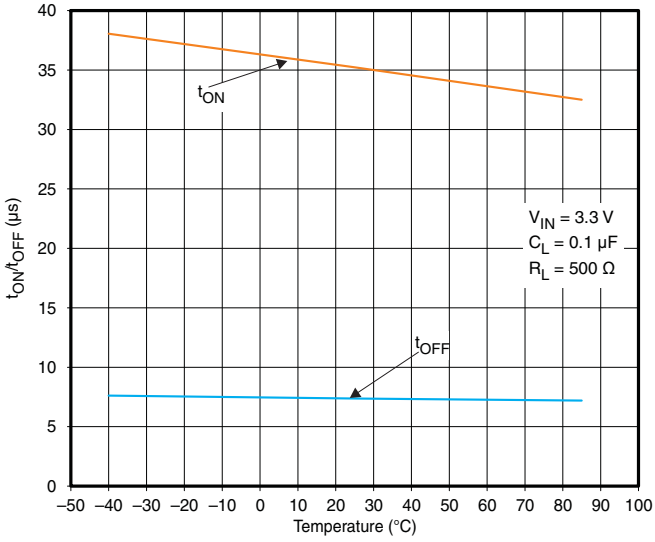


Figure 15. t_{ON}/t_{OFF} vs Temperature

TYPICAL CHARACTERISTICS (continued)

TPS22902B

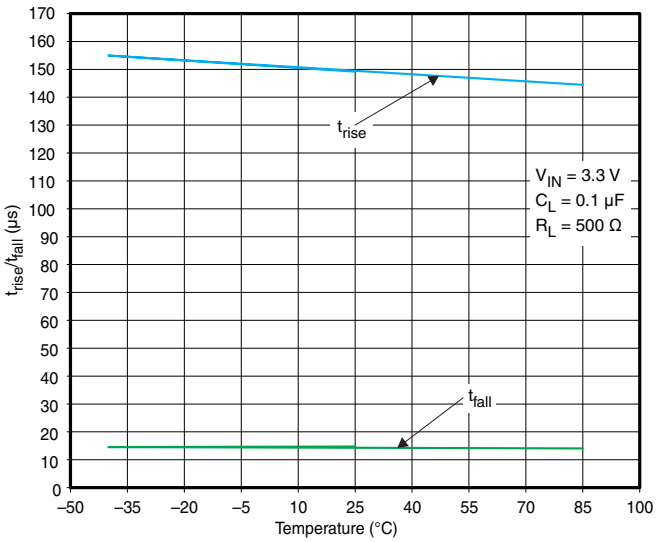


Figure 16. t_{rise}/t_{fall} vs Temperature

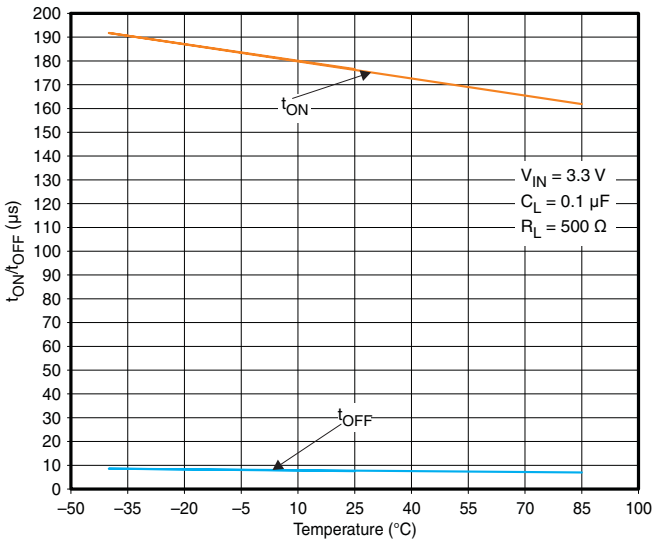


Figure 17. t_{ON}/t_{OFF} vs Temperature

TYPICAL CHARACTERISTICS (continued)

TPS22901 and TPS22902

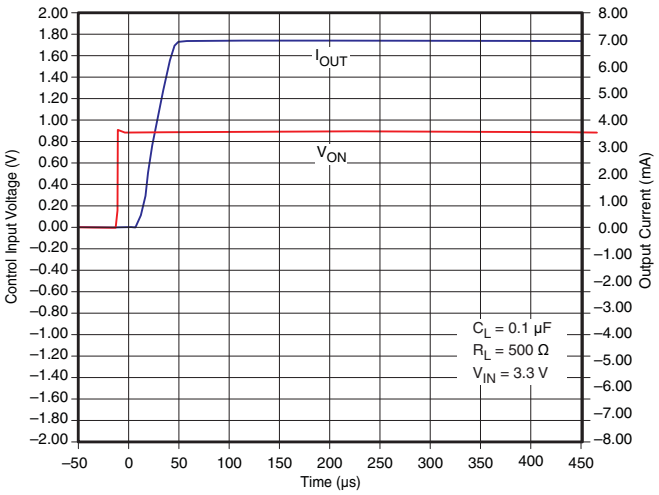


Figure 18. t_{ON} Response

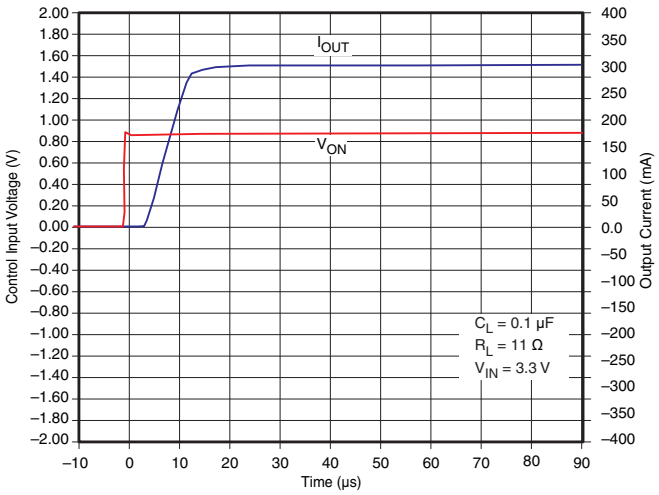


Figure 19. t_{ON} Response

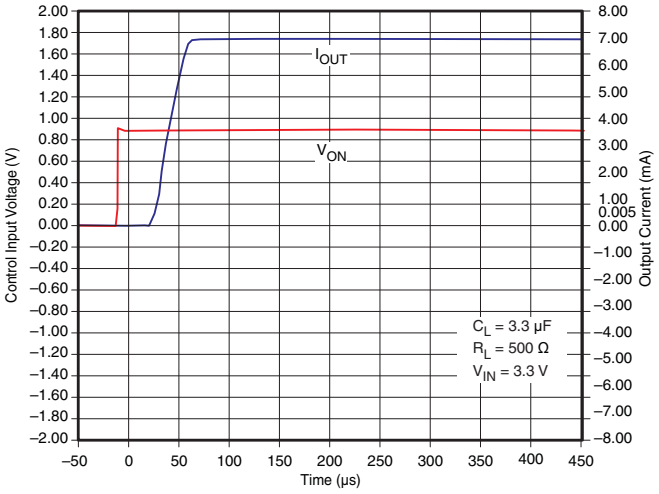


Figure 20. t_{ON} Response

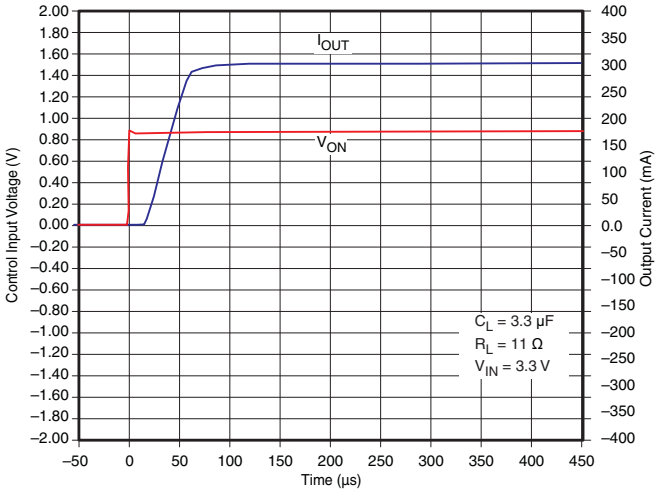


Figure 21. t_{ON} Response

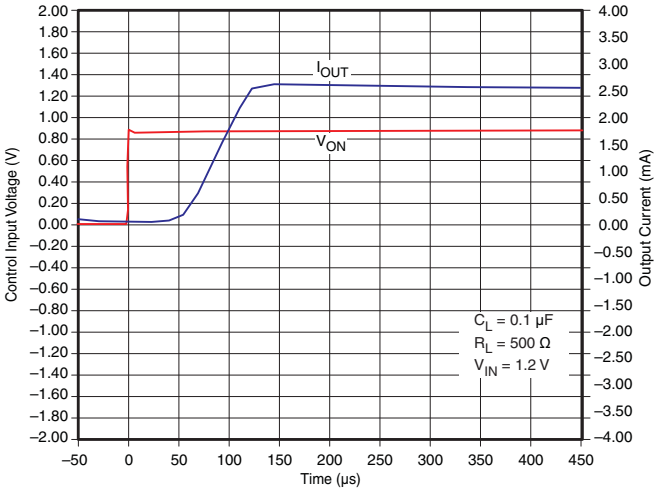


Figure 22. t_{ON} Response

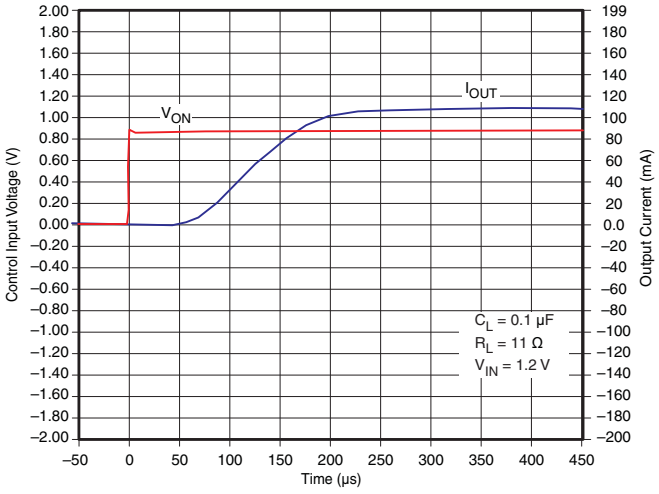


Figure 23. t_{ON} Response

TYPICAL CHARACTERISTICS (continued)

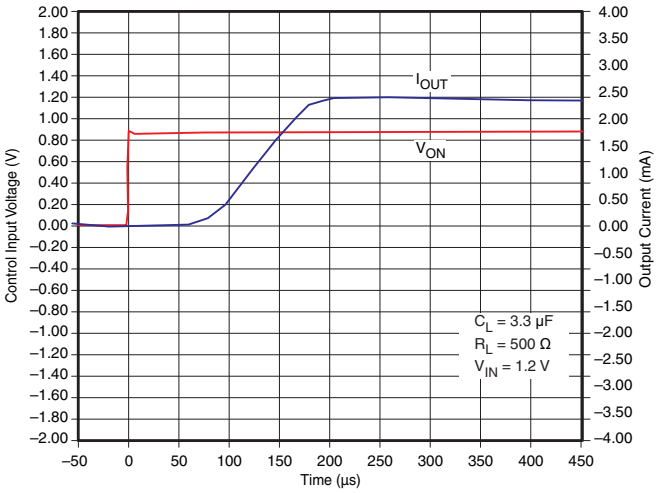


Figure 24. t_{ON} Response

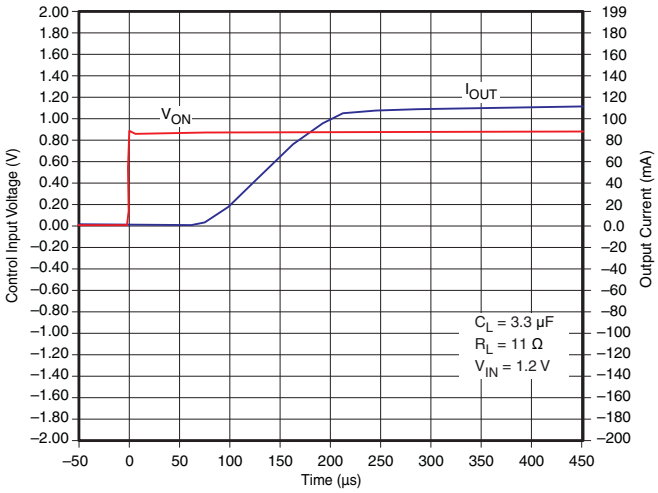


Figure 25. t_{ON} Response

TPS22901

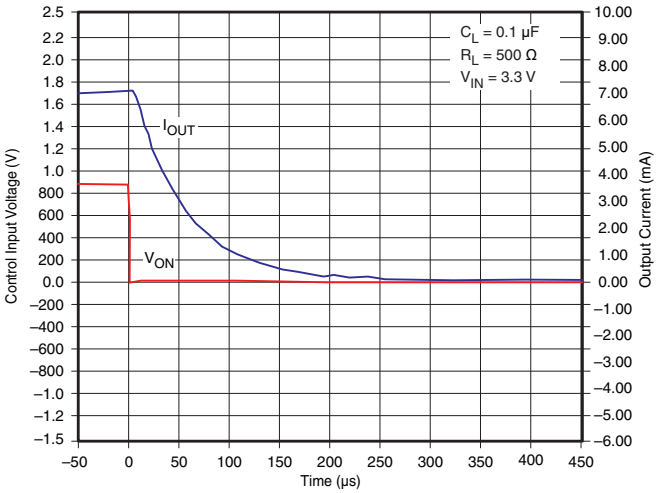


Figure 26. t_{OFF} Response

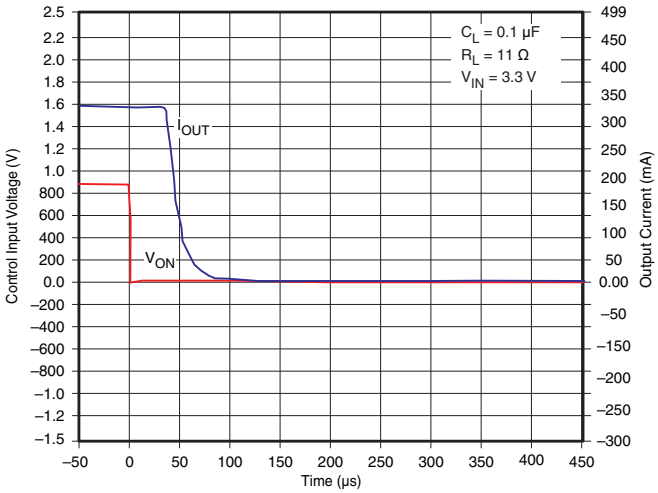


Figure 27. t_{OFF} Response

TYPICAL CHARACTERISTICS (continued)

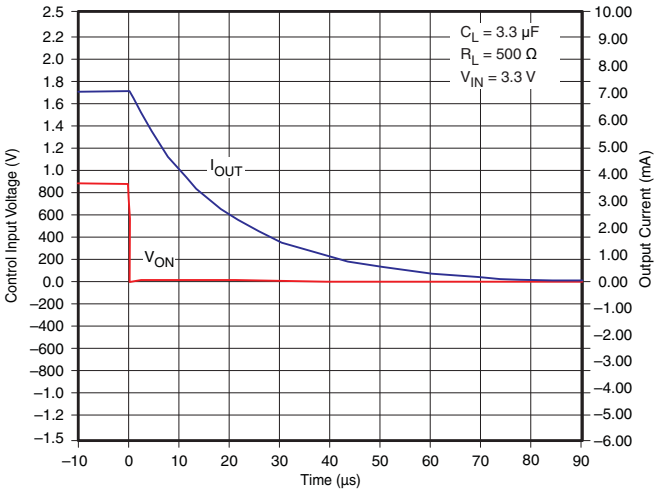


Figure 28. t_{OFF} Response

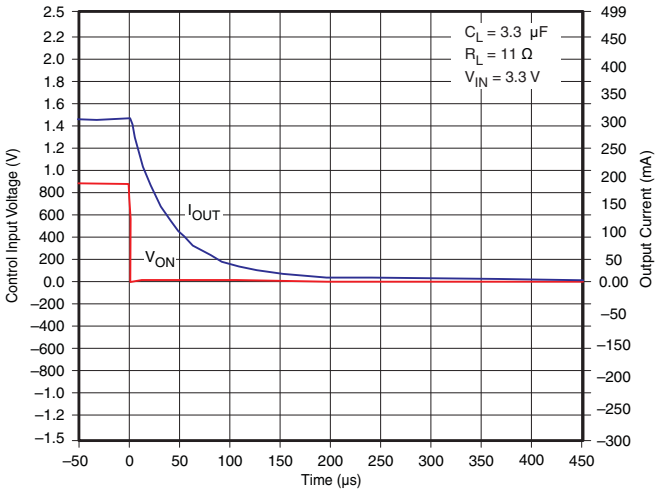


Figure 29. t_{OFF} Response

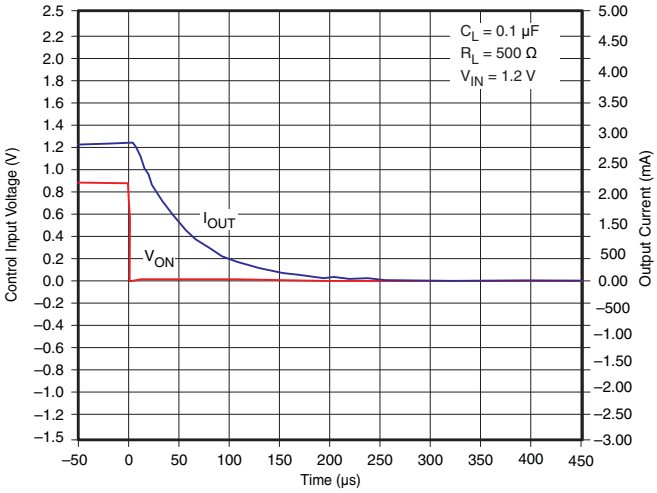


Figure 30. t_{OFF} Response

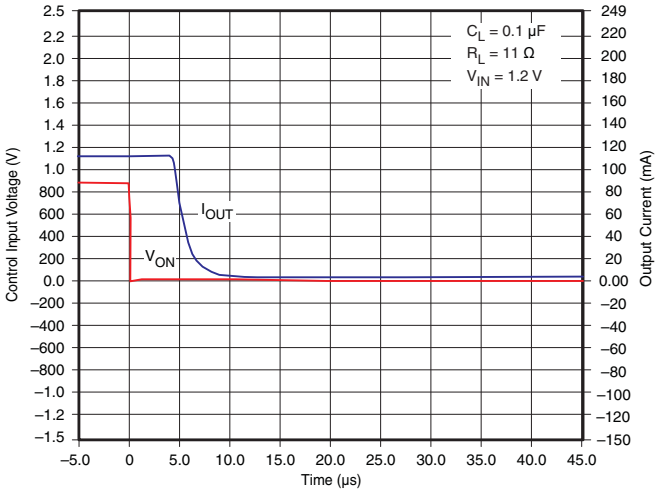


Figure 31. t_{OFF} Response

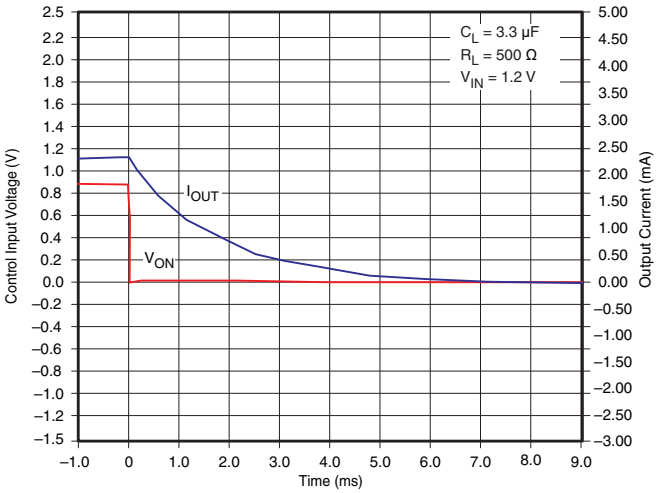


Figure 32. t_{OFF} Response

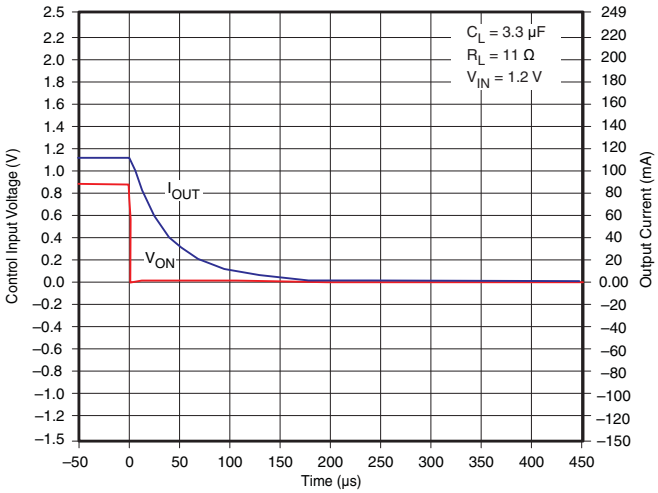


Figure 33. t_{OFF} Response

TYPICAL CHARACTERISTICS (continued)

TPS22902

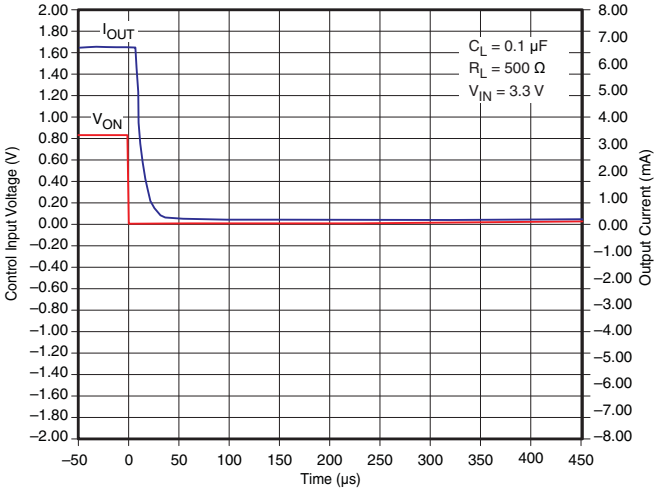


Figure 34. t_{OFF} Response

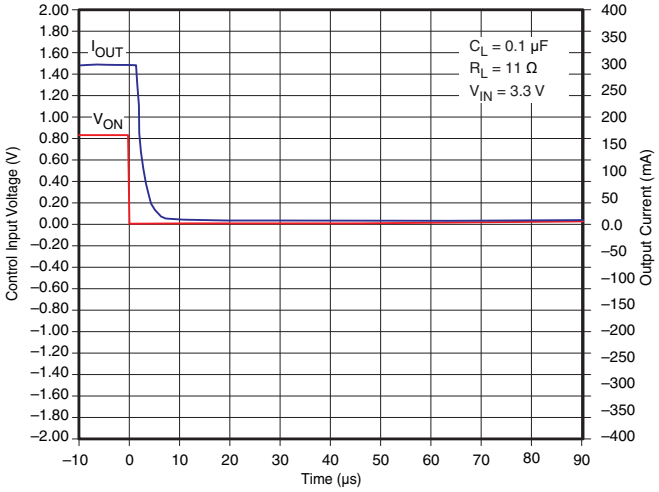


Figure 35. t_{OFF} Response

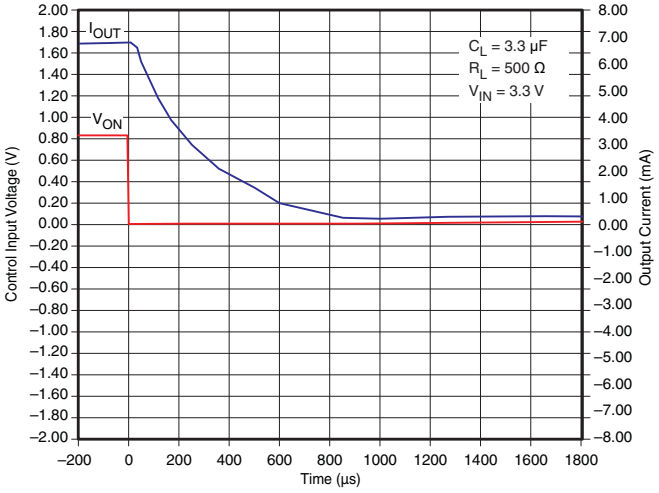


Figure 36. t_{OFF} Response

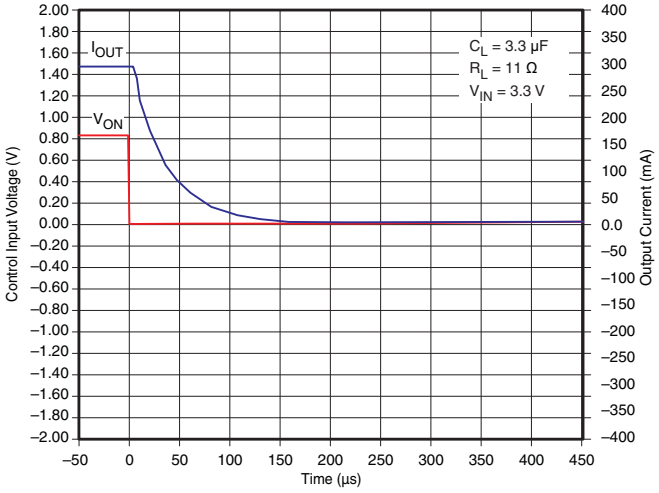


Figure 37. t_{OFF} Response

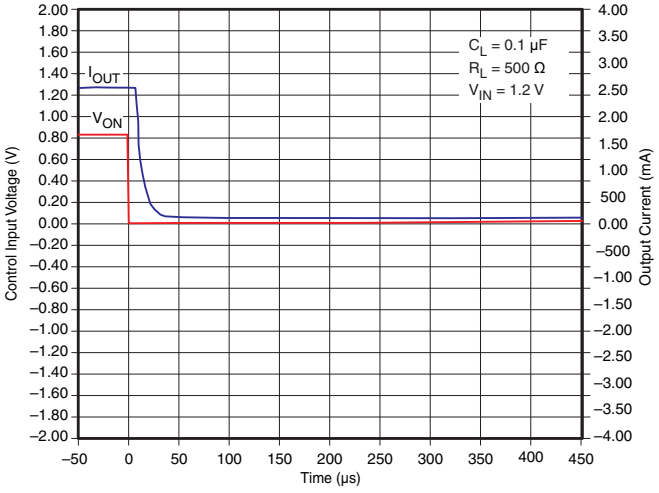


Figure 38. t_{OFF} Response

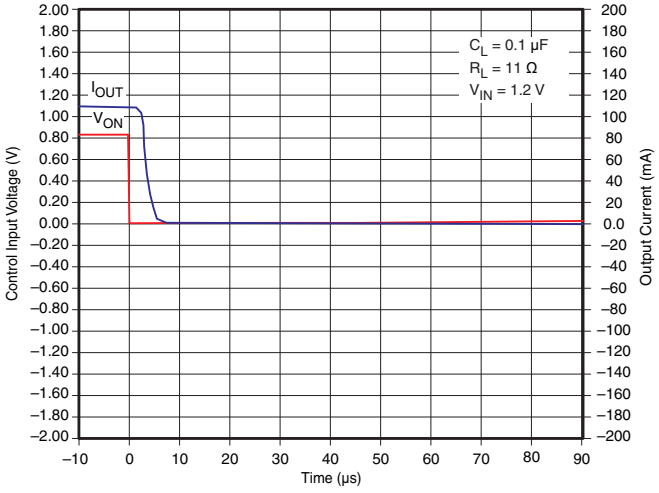


Figure 39. t_{OFF} Response

TYPICAL CHARACTERISTICS (continued)

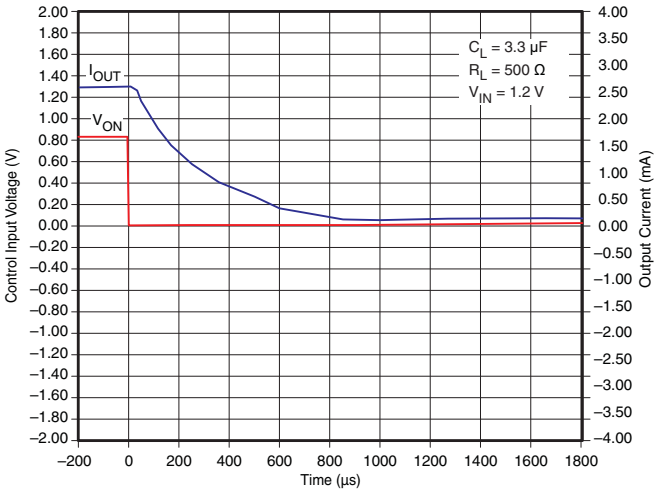


Figure 40. t_{OFF} Response

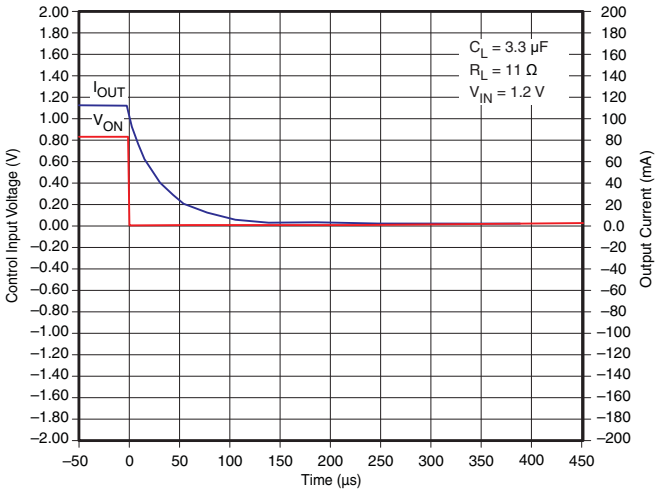


Figure 41. t_{OFF} Response

TPS22902B

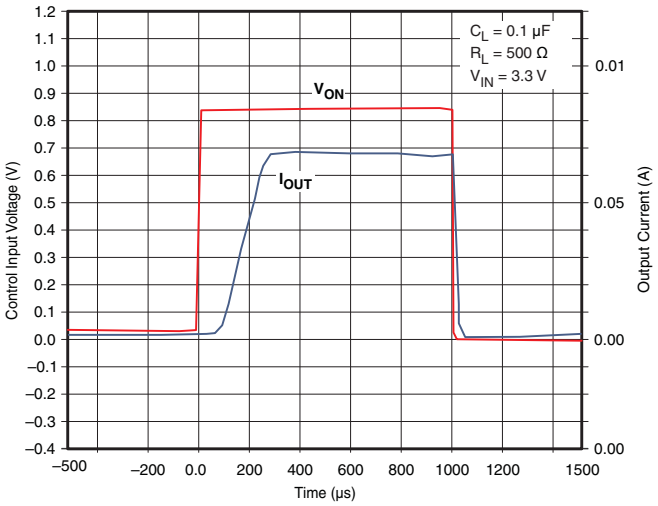


Figure 42. t_{ON} Response

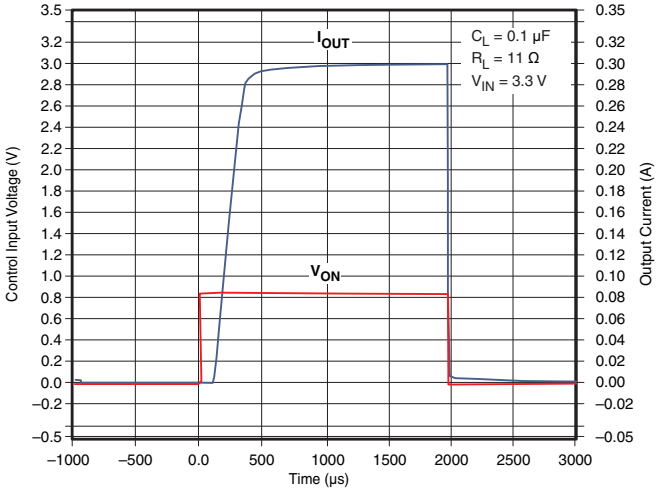


Figure 43. t_{ON} Response

TYPICAL CHARACTERISTICS (continued)

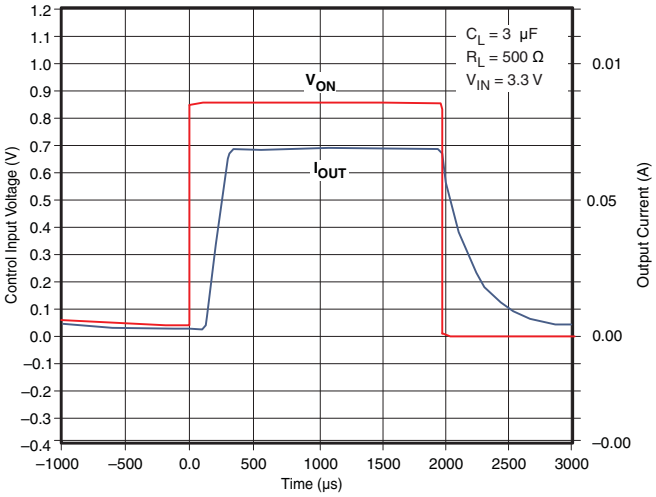


Figure 44. t_{ON} Response

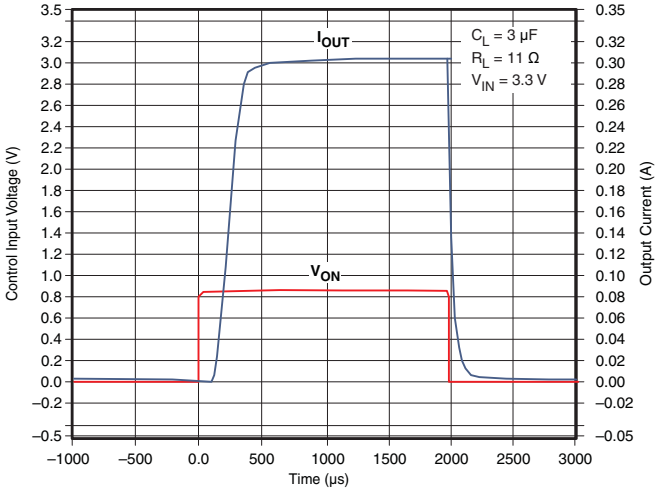


Figure 45. t_{ON} Response

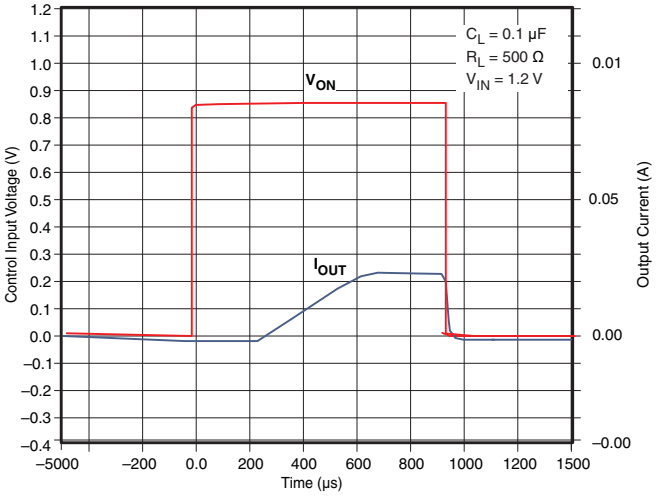


Figure 46. t_{ON} Response

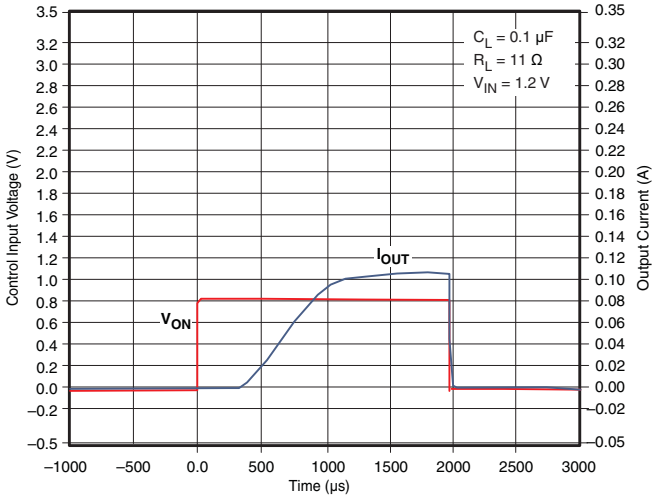


Figure 47. t_{ON} Response

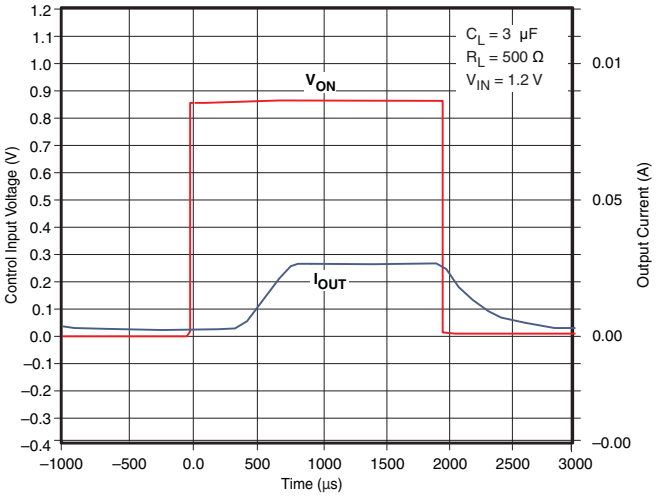


Figure 48. t_{ON} Response

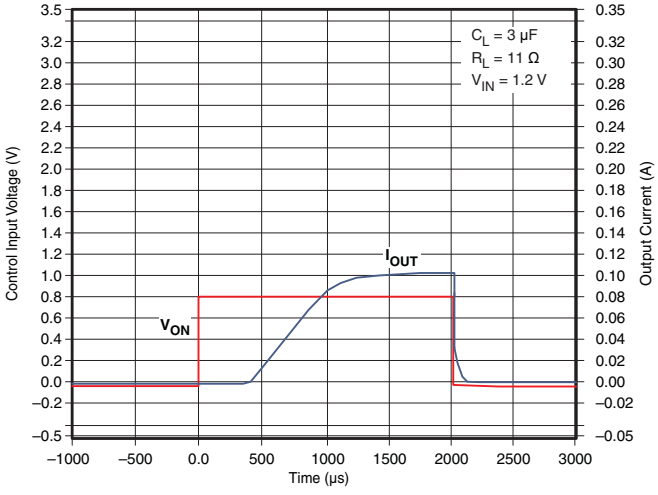


Figure 49. t_{ON} Response

TYPICAL CHARACTERISTICS (continued)

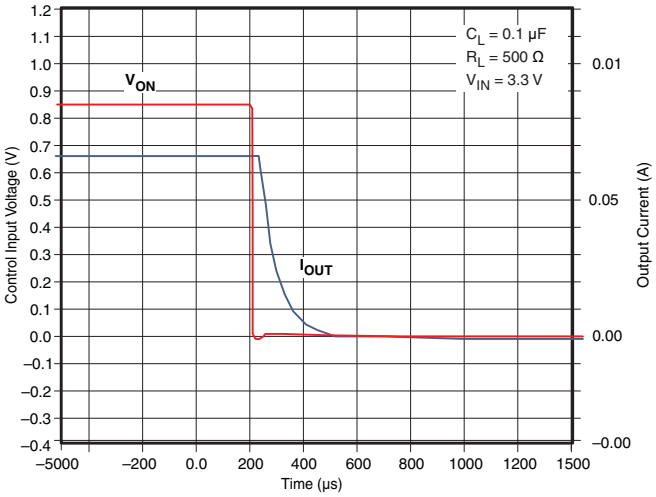


Figure 50. t_{OFF} Response

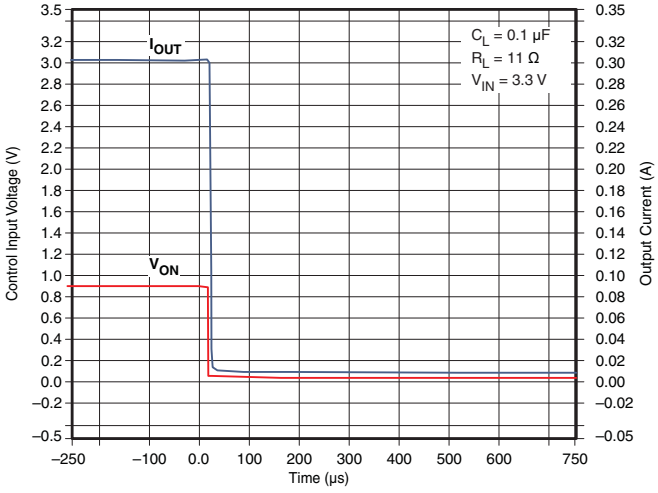


Figure 51. t_{OFF} Response

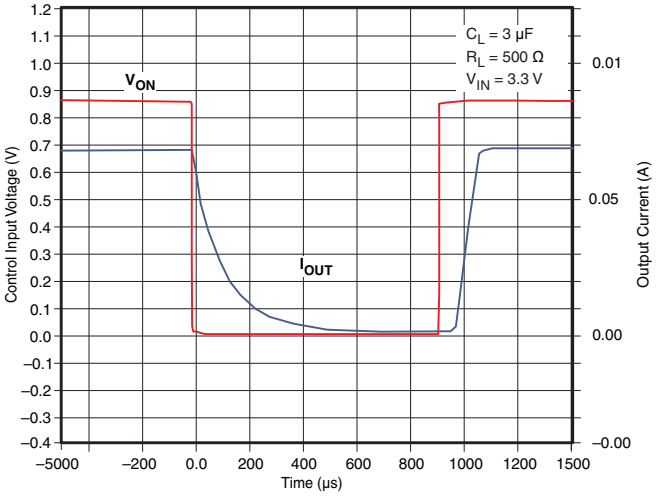


Figure 52. t_{OFF} Response

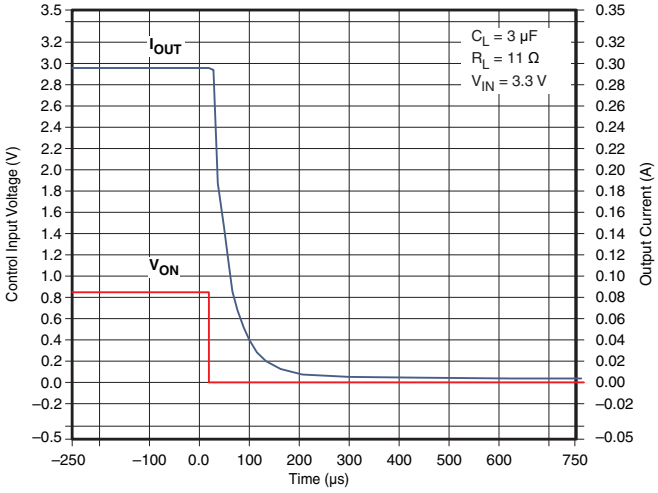


Figure 53. t_{OFF} Response

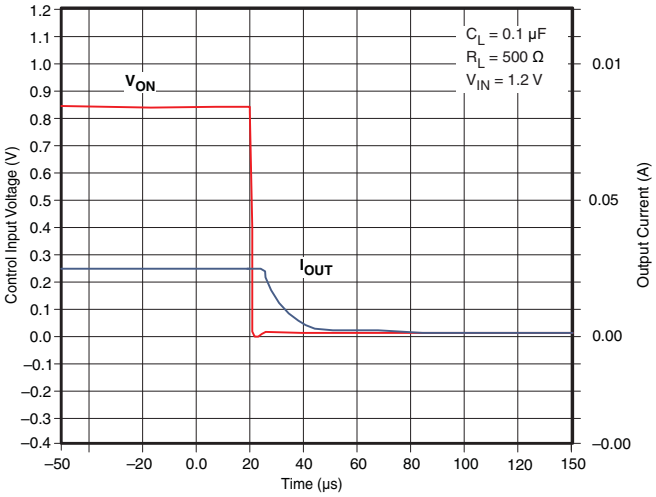


Figure 54. t_{OFF} Response

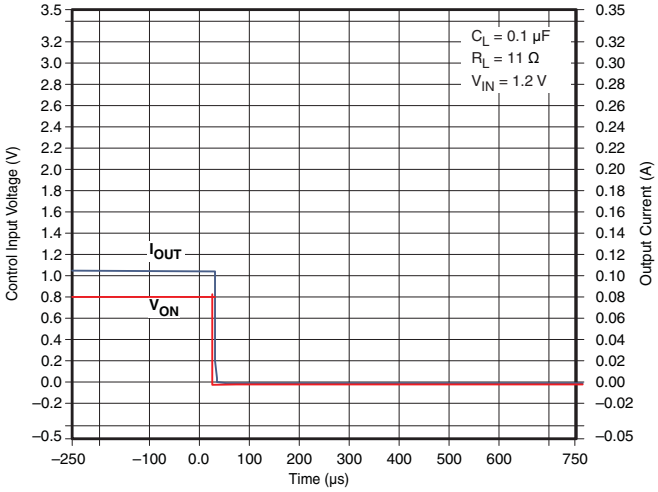


Figure 55. t_{OFF} Response

TYPICAL CHARACTERISTICS (continued)

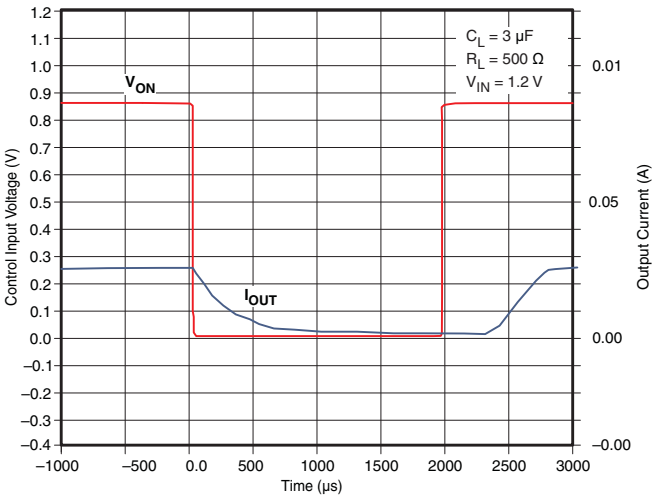


Figure 56. t_{OFF} Response

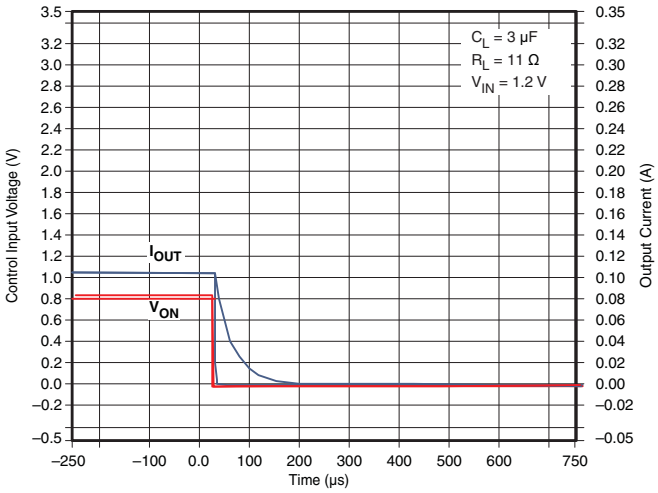
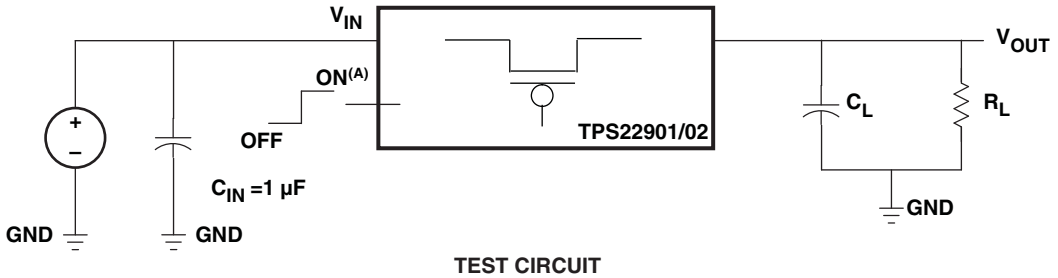
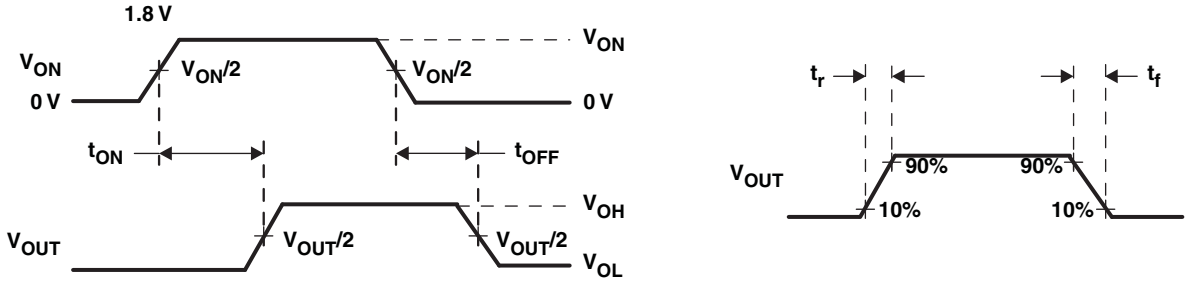


Figure 57. t_{OFF} Response

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT



t_{ON}/t_{OFF} WAVEFORMS

A. t_{rise} and t_{fall} of the control signal is 100 ns.

Figure 58. Test Circuit and t_{ON}/t_{OFF} Waveforms

APPLICATION INFORMATION

ON/OFF Control

The ON pin controls the state of the switch. Activating ON continuously holds the switch in the on state so long as there is no fault. ON is active-high and has a low threshold, making it capable of interfacing with low voltage signals. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V or 3.3-V GPIOs.

Input Capacitor

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{IN} and GND. A 1-µF ceramic capacitor, C_{IN}, place close to the pins is usually sufficient. Higher values of C_{IN} can be use to further reduce the voltage drop during high current application. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor, this in order to avoid excessive voltage drop.

Output Capacitor

Due to the integral body diode in the PMOS switch, a C_{IN} greater than C_L is highly recommended. A C_L greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN}.

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces for V_{IN}, V_{OUT}, and GND helps minimize the parasitic electrical effects along with minimizing the case-to-ambient thermal impedance.

PACKAGING INFORMATION

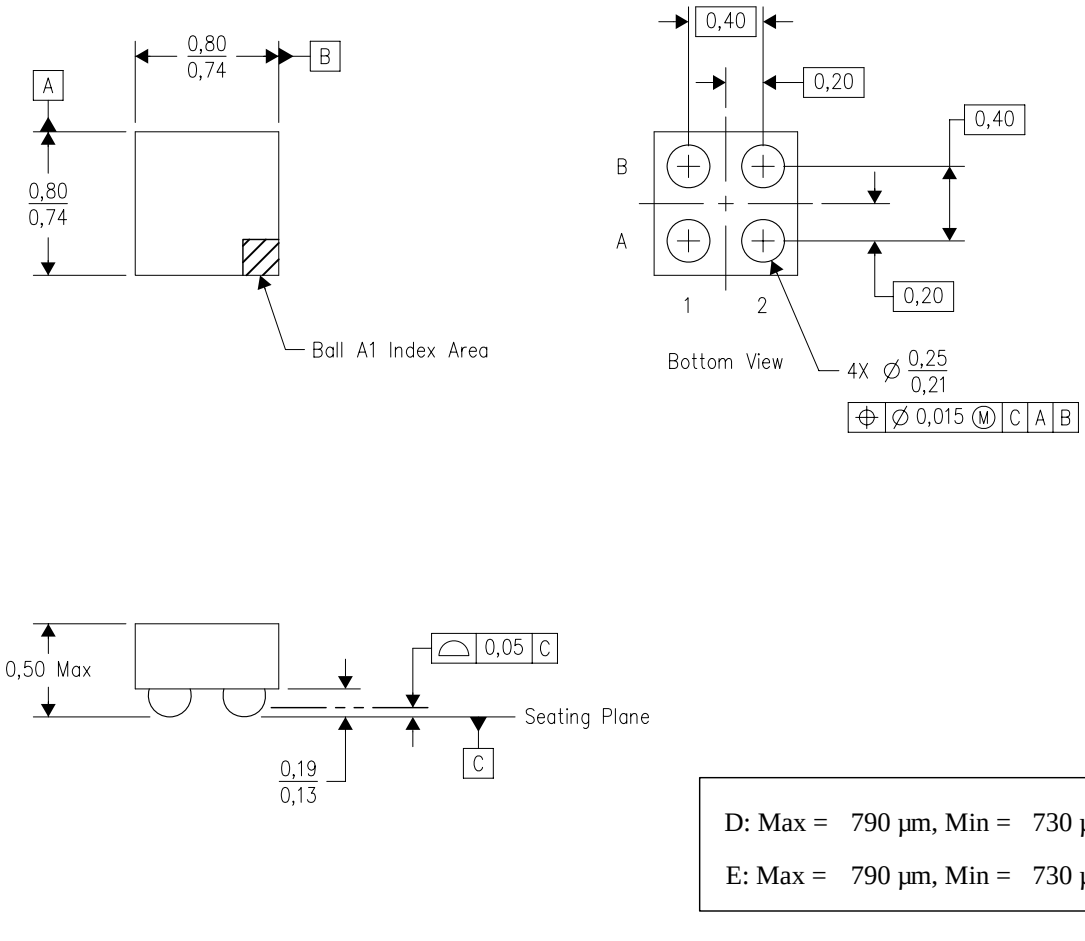
Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
TPS22901YFPR	ACTIVE	DSBGA	YFP	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
TPS22902BYFPR	ACTIVE	DSBGA	YFP	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
TPS22902YFPR	ACTIVE	DSBGA	YFP	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

YFP (S–XBGA–N4) DIE–SIZE BALL GRID ARRAY



D: Max = 790 µm, Min = 730 µm

E: Max = 790 µm, Min = 730 µm

4206986–2/P 04/2010

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. NanoFree™ package configuration.
D. This is a Pb–free solder ball design.

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